

Features

- 650-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives







Part Number	Package	Qty(PCS)		
C6D08065G-TR	TO-263	800		

1 TO-263

Case ∘

Maximum Ratings (T_c = 25 $^{\circ}$ C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions
V _{RRM}	Repetitive Peak Reverse Voltage	650	V	
V _{RSM}	Surge Peak Reverse Voltage	650	V	
l _F	Continuous Forward Current	27.5 12.7 8	А	T _c =25°C T _c =135°C T _c =156°C
I _{FRM}	Repetitive Peak Forward Surge Current	44	А	T _c =25°C, t _p = 10 ms, Half Sine Wave
I _{FSM}	Non-Repetitive Peak Forward Surge Current	88	Α	T_c =25°C, t_p = 10 ms, Half Sine Wave
P _{tot}	Power Dissipation	103 45	W	T _c =25°C T _c =110°C
T_{J} , T_{stg}	Operating Junction and Storage Temperature	-55 to +175	°C	
∫i²dt	i²dt value	38.72	A ² s	T _c =25°C, t _p = 10 ms, Half Sine Wave



Electrical Characteristics

Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions
V _{DC}	DC Blocking Voltage	650			V	
V _F	Forward Voltage		1.38 1.65	1.7 2	V	I _F = 8 A T _J =25°C I _F = 8 A T _J =175°C
I _R	Reverse Current		0.2 2	50 100	μΑ	$V_R = 650 \text{ V } T_J = 25^{\circ}\text{C}$ $V_R = 650 \text{ V } T_J = 175^{\circ}\text{C}$
Q _c	Total Capacitive Charge		28		nC	V _R = 400 V T _J = 25°C
С	Total Capacitance		541 55 54		pF	V _R = 0 V, T _J = 25°C, f = 1 MHz V _R = 200 V, T _J = 25°C, f = 1 MHz V _R = 400 V, T _J = 25°C, f = 1 MHz
E _c	Capacitance Stored Energy		7		μJ	V _R = 400 V

Thermal Characteristics

Symbol	Parameter	Тур.	Unit
R _{eJC}	Thermal Resistance from Junction to Case	1.45	°C/W

Typical Performance

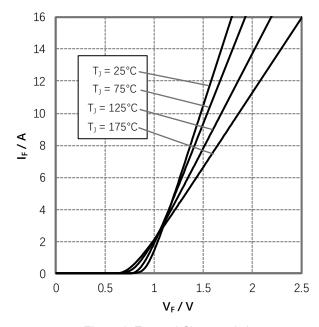


Figure 1. Forward Characteristics

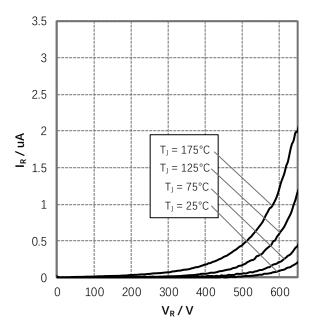
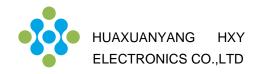


Figure 2. Reverse Characteristics



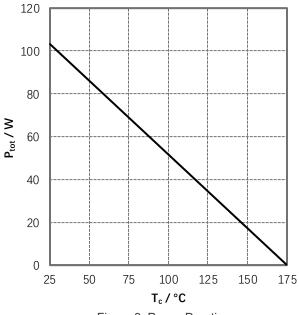


Figure 3. Power Derating

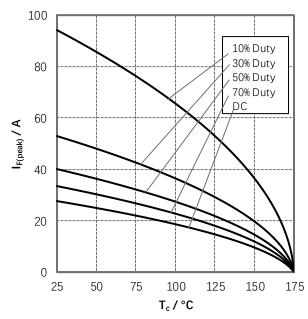


Figure 4. Current Derating

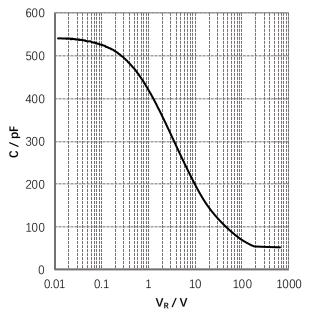


Figure 5. Capacitance vs. Reverse Voltage

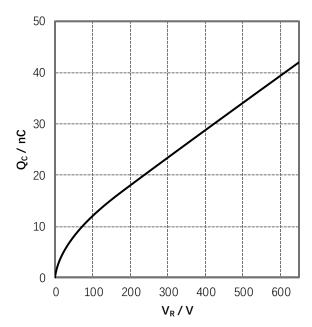


Figure 6. Total Capacitance Charge vs. Reverse Voltage

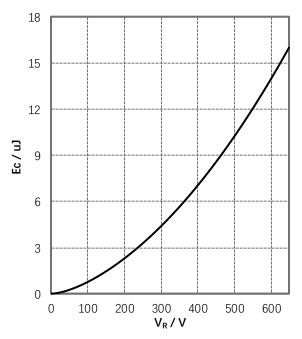


Figure 7. Capacitance Stored Energy

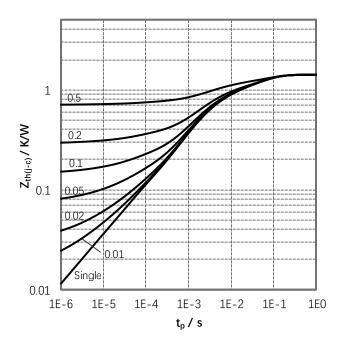
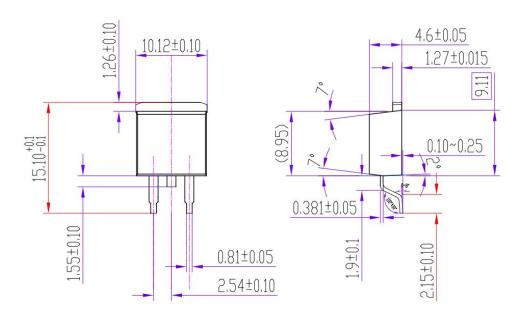
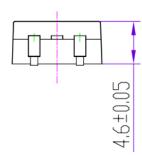
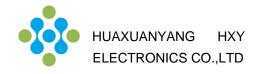


Figure 8. Transient Thermal Impedance

Package Information TO-263







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